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## **FNA40860/B2**

### **Smart Power Module**

#### **Features**

- 600V-8A 3-phase IGBT inverter bridge including control ICs for gate driving and protection
- Easy PCB layout due to built-in bootstrap diode and  $V_S$  output
- Divided negative dc-link terminals for inverter current sensing applications
- Single-grounded power supply due to built-in HVIC
- Built-in thermistor for over-temperature monitoring
- Isolation rating of 2000Vrms/min.

#### **Applications**

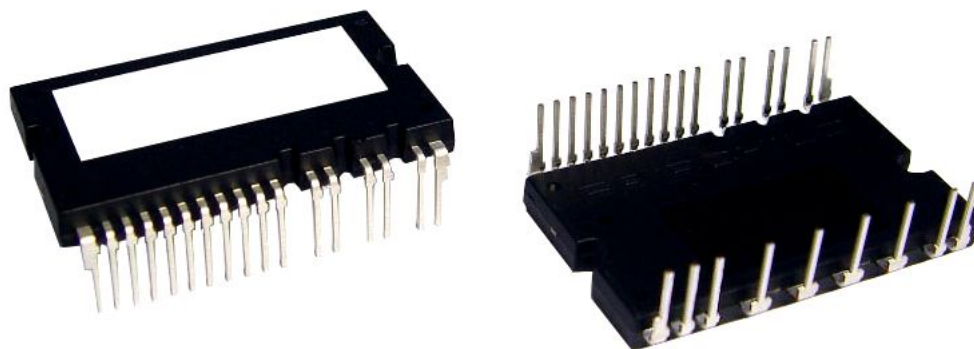
- AC 100V ~ 253V three-phase inverter drive for small power ac motor drives
- Home appliances applications like air conditioner and refrigerator

#### **General Description**

It is an advanced motion-smart power module (Motion-SPM™) that Fairchild has newly developed and designed to provide very compact and high performance ac motor drives mainly targeting low-power inverter-driven application like air conditioner and refrigerator. It combines optimized circuit protection and drive matched to low-loss IGBTs. System reliability is further enhanced by the integrated under-voltage lock-out protection, short-circuit protection, and temperature monitoring. The high speed built-in HVIC provides opto-coupler-less single-supply IGBT gate driving capability that further reduce the overall size of the inverter system design. Each phase current of inverter can be monitored separately due to the divided negative dc terminals.

#### **Additional Information**

For further information, please see AN-9070 and FEB305-001 in <http://www.fairchildsemi.com>



**Figure 1.**

## Integrated Power Functions

- 600V-8A IGBT inverter for three-phase DC/AC power conversion (Please refer to Figure 3)

## Integrated Drive, Protection and System Control Functions

- For inverter high-side IGBTs: Gate drive circuit, High voltage isolated high-speed level shifting  
Control circuit under-voltage (UV) protection
- For inverter low-side IGBTs: Gate drive circuit, Short circuit protection (SC)  
Control supply circuit under-voltage (UV) protection
- Fault signaling: Corresponding to UV (Low-side supply) and SC faults
- Input interface: 3.3/5V CMOS compatible, Schmitt trigger input

## Pin Configuration

### Top View

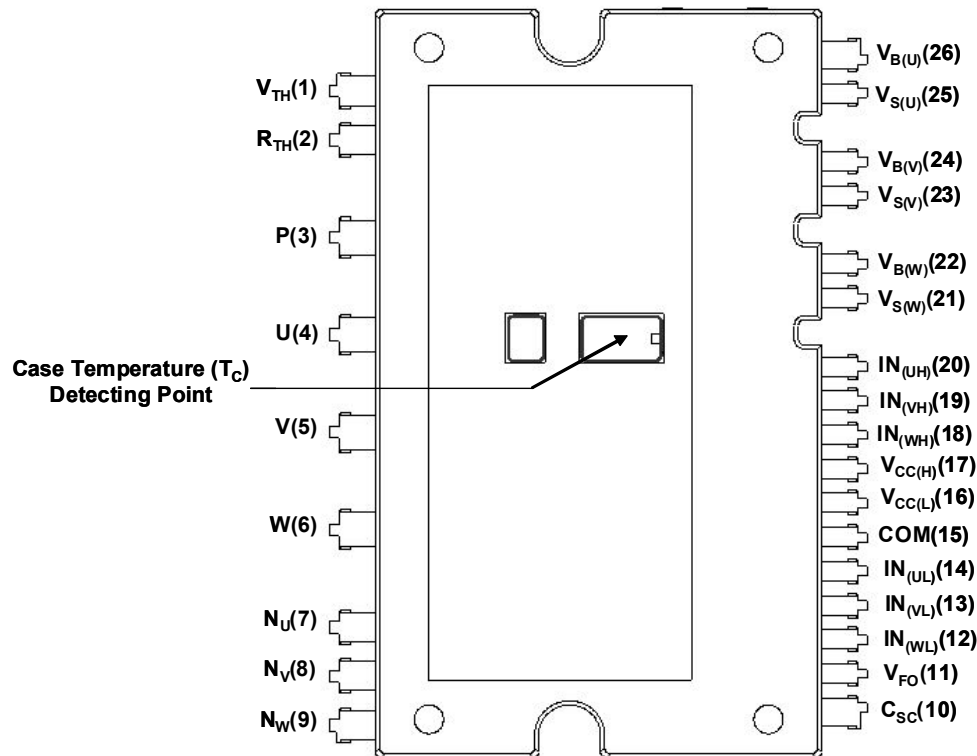
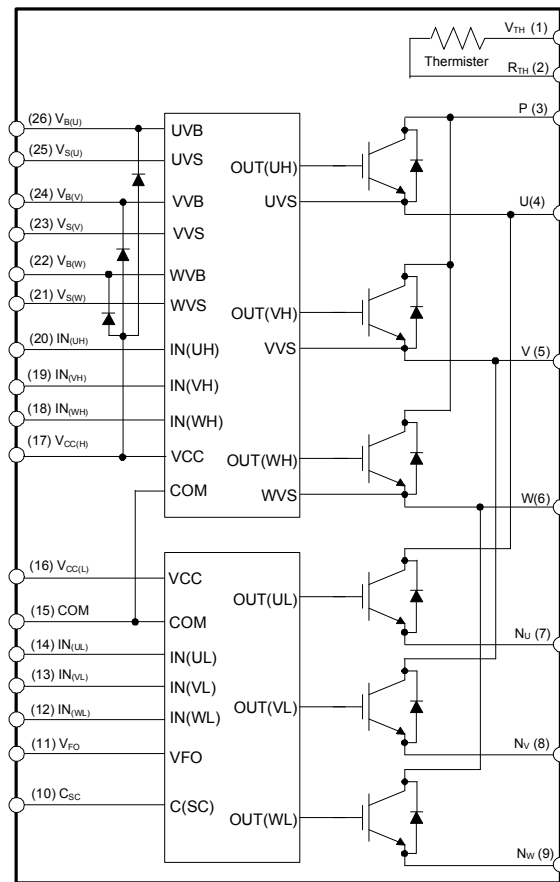


Figure 2.

## Pin Descriptions

| Pin Number | Pin Name    | Pin Description                                                   |
|------------|-------------|-------------------------------------------------------------------|
| 1          | $V_{TH}$    | Thermistor Bias Voltage                                           |
| 2          | $R_{TH}$    | Series Resistor for the Use of Thermistor (Temperature Detection) |
| 3          | P           | Positive DC–Link Input                                            |
| 4          | U           | Output for U Phase                                                |
| 5          | V           | Output for V Phase                                                |
| 6          | W           | Output for W Phase                                                |
| 7          | $N_U$       | Negative DC–Link Input for U Phase                                |
| 8          | $N_V$       | Negative DC–Link Input for V Phase                                |
| 9          | $N_W$       | Negative DC–Link Input for W Phase                                |
| 10         | $C_{SC}$    | Capacitor (Low-pass Filter) for Short-Current Detection Input     |
| 11         | $V_{FO}$    | Fault Output                                                      |
| 12         | $IN_{(WL)}$ | Signal Input for Low-side W Phase                                 |
| 13         | $IN_{(VL)}$ | Signal Input for Low-side V Phase                                 |
| 14         | $IN_{(UL)}$ | Signal Input for Low-side U Phase                                 |
| 15         | COM         | Common Supply Ground                                              |
| 16         | $V_{CC(L)}$ | Low-Side Common Bias Voltage for IC and IGBTs Driving             |
| 17         | $V_{CC(H)}$ | High-Side Common Bias Voltage for IC and IGBTs Driving            |
| 18         | $IN_{(WH)}$ | Signal Input for High-side W Phase                                |
| 19         | $IN_{(VH)}$ | Signal Input for High-side V Phase                                |
| 20         | $IN_{(UH)}$ | Signal Input for High-side U Phase                                |
| 21         | $V_{S(W)}$  | High-side Bias Voltage Ground for W Phase IGBT Driving            |
| 22         | $V_{B(W)}$  | High-side Bias Voltage for W Phase IGBT Driving                   |
| 23         | $V_{S(V)}$  | High-side Bias Voltage Ground for V Phase IGBT Driving            |
| 24         | $V_{B(V)}$  | High-side Bias Voltage for V Phase IGBT Driving                   |
| 25         | $V_{S(U)}$  | High-side Bias Voltage Ground for U Phase IGBT Driving            |
| 26         | $V_{B(U)}$  | High-side Bias Voltage for U Phase IGBT Driving                   |

## Internal Equivalent Circuit and Input/Output Pins



### Note:

- 1) Inverter high-side is composed of three IGBTs, freewheeling diodes and one control IC for each IGBT.
- 2) Inverter low-side is composed of three IGBTs, freewheeling diodes and one control IC for each IGBT. It has gate drive and protection functions.
- 3) Inverter power side is composed of four inverter dc-link input terminals and three inverter output terminals.

**Figure 3.**

**Absolute Maximum Ratings** ( $T_J = 25^{\circ}\text{C}$ , Unless Otherwise Specified)**Inverter Part**

| Symbol                 | Parameter                          | Conditions                                                                                                | Rating    | Units              |
|------------------------|------------------------------------|-----------------------------------------------------------------------------------------------------------|-----------|--------------------|
| $V_{PN}$               | Supply Voltage                     | Applied between P- $N_U$ , $N_V$ , $N_W$                                                                  | 450       | V                  |
| $V_{PN(\text{Surge})}$ | Supply Voltage (Surge)             | Applied between P- $N_U$ , $N_V$ , $N_W$                                                                  | 500       | V                  |
| $V_{CES}$              | Collector-emitter Voltage          |                                                                                                           | 600       | V                  |
| $\pm I_C$              | Each IGBT Collector Current        | $T_C = 25^{\circ}\text{C}$ , $T_J < 150^{\circ}\text{C}$                                                  | 8         | A                  |
| $\pm I_{CP}$           | Each IGBT Collector Current (Peak) | $T_C = 25^{\circ}\text{C}$ , $T_J < 150^{\circ}\text{C}$ , $V_{PN} = 300\text{V}$ , Under 1ms Pulse Width | 24        | A                  |
| $P_C$                  | Collector Dissipation              | $T_C = 25^{\circ}\text{C}$ per One Chip                                                                   | 32        | W                  |
| $T_J$                  | Operating Junction Temperature     | (Note 1)                                                                                                  | -40 ~ 150 | $^{\circ}\text{C}$ |

**Note:**

1. The maximum junction temperature rating of the power chips integrated within the SPM is  $150^{\circ}\text{C}$ .

**Control Part**

| Symbol   | Parameter                      | Conditions                                                                                              | Rating             | Units |
|----------|--------------------------------|---------------------------------------------------------------------------------------------------------|--------------------|-------|
| $V_{CC}$ | Control Supply Voltage         | Applied between $V_{CC(H)}$ , $V_{CC(L)}$ - COM                                                         | 20                 | V     |
| $V_{BS}$ | High-side Control Bias Voltage | Applied between $V_{B(U)}$ - $V_{S(U)}$ , $V_{B(V)}$ - $V_{S(V)}$ , $V_{B(W)}$ - $V_{S(W)}$             | 20                 | V     |
| $V_{IN}$ | Input Signal Voltage           | Applied between $IN_{(UH)}$ , $IN_{(VH)}$ , $IN_{(WH)}$ , $IN_{(UL)}$ , $IN_{(VL)}$ , $IN_{(WL)}$ - COM | -0.3~ $V_{CC}+0.3$ | V     |
| $V_{FO}$ | Fault Output Supply Voltage    | Applied between $V_{FO}$ - COM                                                                          | -0.3~ $V_{CC}+0.3$ | V     |
| $I_{FO}$ | Fault Output Current           | Sink Current at $V_{FO}$ Pin                                                                            | 1                  | mA    |
| $V_{SC}$ | Current Sensing Input Voltage  | Applied between $C_{SC}$ - COM                                                                          | -0.3~ $V_{CC}+0.3$ | V     |

**Bootstrap Diode Part**

| Symbol    | Parameter                          | Conditions                                         | Rating    | Units              |
|-----------|------------------------------------|----------------------------------------------------|-----------|--------------------|
| $V_{RRM}$ | Maximum Repetitive Reverse Voltage |                                                    | 600       | V                  |
| $I_F$     | Forward Current                    | $T_C = 25^{\circ}\text{C}$                         | 0.5       | A                  |
| $I_{FP}$  | Forward Current (Peak)             | $T_C = 25^{\circ}\text{C}$ , Under 1ms Pulse Width | 1         | A                  |
| $T_J$     | Operating Junction Temperature     |                                                    | -40 ~ 150 | $^{\circ}\text{C}$ |

**Total System**

| Symbol                | Parameter                                                                  | Conditions                                                                                                            | Rating    | Units              |
|-----------------------|----------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------|-----------|--------------------|
| $V_{PN(\text{PROT})}$ | Self Protection Supply Voltage Limit (Short Circuit Protection Capability) | $V_{CC} = V_{BS} = 13.5 \sim 16.5\text{V}$<br>$T_J = 150^{\circ}\text{C}$ , Non-repetitive, less than 2 $\mu\text{s}$ | 400       | V                  |
| $T_{STG}$             | Storage Temperature                                                        |                                                                                                                       | -40 ~ 125 | $^{\circ}\text{C}$ |
| $V_{ISO}$             | Isolation Voltage                                                          | 60Hz, Sinusoidal, AC 1 minute, Connection Pins to heat sink plate                                                     | 2000      | $V_{rms}$          |

**Thermal Resistance**

| Symbol         | Parameter                           | Conditions                          | Min. | Typ. | Max. | Units                |
|----------------|-------------------------------------|-------------------------------------|------|------|------|----------------------|
| $R_{th(j-c)Q}$ | Junction to Case Thermal Resistance | Inverter IGBT part (per 1/6 module) | -    | -    | 3.8  | $^{\circ}\text{C/W}$ |
| $R_{th(j-c)F}$ |                                     | Inverter FWD part (per 1/6 module)  | -    | -    | 4.8  | $^{\circ}\text{C/W}$ |

**Note:**

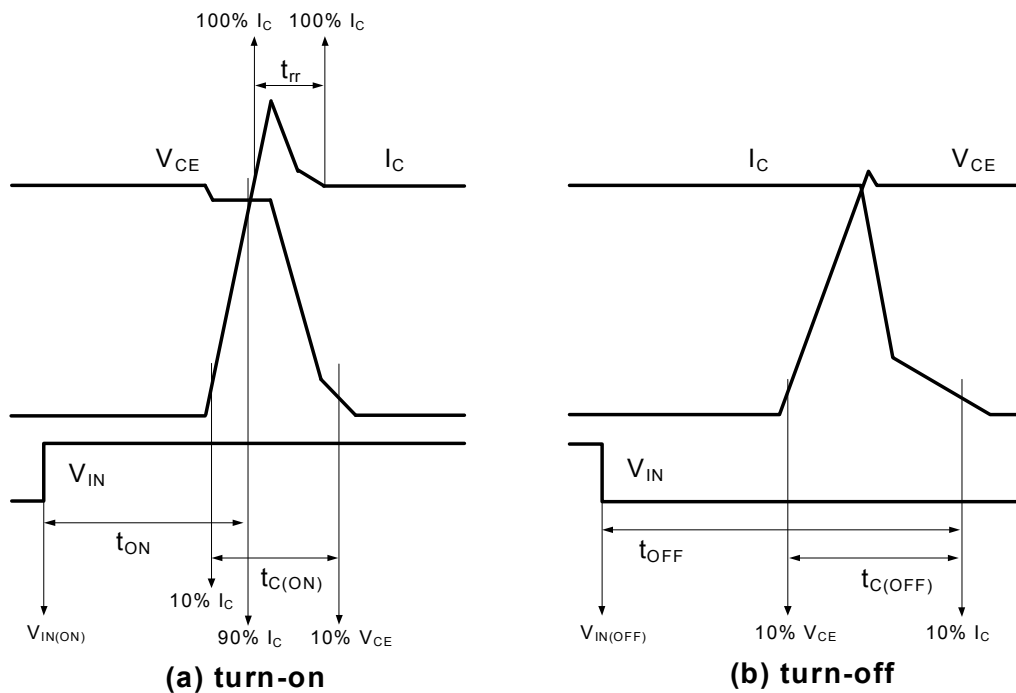
2. For the measurement point of case temperature( $T_C$ ), please refer to Figure 2.

**Electrical Characteristics** ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)**Inverter Part**

| Symbol        | Parameter                            | Conditions                                                                                                                                                                             | Min. | Typ. | Max. | Units         |
|---------------|--------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|---------------|
| $V_{CE(SAT)}$ | Collector-Emitter Saturation Voltage | $V_{CC} = V_{BS} = 15\text{V}$<br>$V_{IN} = 5\text{V}$<br>$I_C = 8\text{A}$ , $T_J = 25^\circ\text{C}$                                                                                 | -    | 1.7  | 2.2  | V             |
| $V_F$         | FWD Forward Voltage                  | $V_{IN} = 0\text{V}$<br>$I_F = 8\text{A}$ , $T_J = 25^\circ\text{C}$                                                                                                                   | -    | 1.7  | 2.2  | V             |
| HS            | $t_{ON}$                             | $V_{PN} = 300\text{V}$ , $V_{CC} = V_{BS} = 15\text{V}$ , $I_C = 8\text{A}$<br>$T_J = 25^\circ\text{C}$<br>$V_{IN} = 0\text{V} \leftrightarrow 5\text{V}$ , Inductive Load<br>(Note 3) | 0.45 | 0.75 | 1.25 | $\mu\text{s}$ |
|               | $t_{C(ON)}$                          |                                                                                                                                                                                        | -    | 0.20 | 0.45 | $\mu\text{s}$ |
|               | $t_{OFF}$                            |                                                                                                                                                                                        | -    | 0.80 | 1.30 | $\mu\text{s}$ |
|               | $t_{C(OFF)}$                         |                                                                                                                                                                                        | -    | 0.30 | 0.55 | $\mu\text{s}$ |
|               | $t_{rr}$                             |                                                                                                                                                                                        | -    | 0.15 | -    | $\mu\text{s}$ |
| LS            | $t_{ON}$                             | $V_{PN} = 300\text{V}$ , $V_{CC} = V_{BS} = 15\text{V}$ , $I_C = 8\text{A}$<br>$T_J = 25^\circ\text{C}$<br>$V_{IN} = 0\text{V} \leftrightarrow 5\text{V}$ , Inductive Load<br>(Note 3) | 0.45 | 0.75 | 1.25 | $\mu\text{s}$ |
|               | $t_{C(ON)}$                          |                                                                                                                                                                                        | -    | 0.20 | 0.45 | $\mu\text{s}$ |
|               | $t_{OFF}$                            |                                                                                                                                                                                        | -    | 0.80 | 1.30 | $\mu\text{s}$ |
|               | $t_{C(OFF)}$                         |                                                                                                                                                                                        | -    | 0.30 | 0.55 | $\mu\text{s}$ |
|               | $t_{rr}$                             |                                                                                                                                                                                        | -    | 0.15 | -    | $\mu\text{s}$ |
| $I_{CES}$     | Collector-Emitter Leakage Current    | $V_{CE} = V_{CES}$                                                                                                                                                                     | -    | -    | 1    | mA            |

**Note:**

3.  $t_{ON}$  and  $t_{OFF}$  include the propagation delay time of the internal drive IC.  $t_{C(ON)}$  and  $t_{C(OFF)}$  are the switching time of IGBT itself under the given gate driving condition internally. For the detailed information, please see Figure 4.

**Figure 4. Switching Time Definition**

## Switching Loss (Typical)

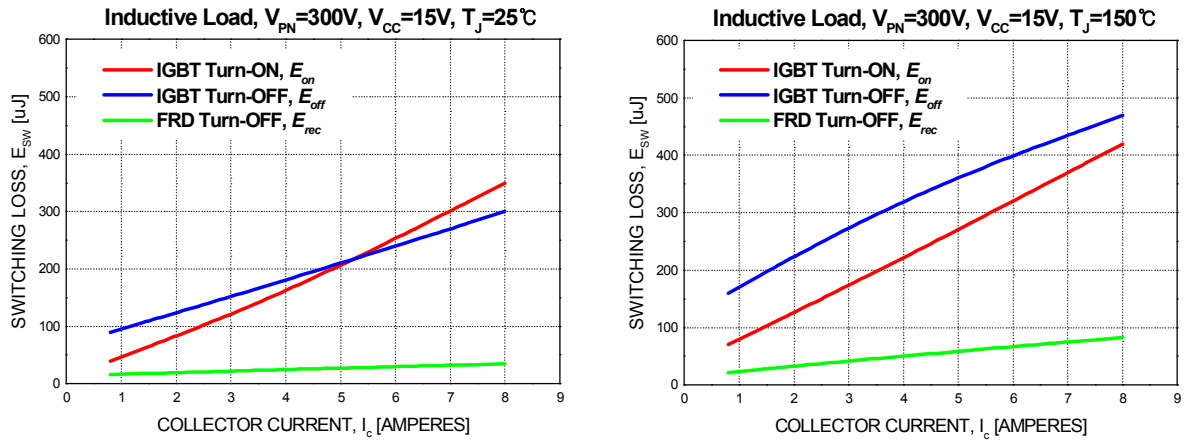


Figure 5. Switching Loss Characteristics

## Control Part

| Symbol        | Parameter                               | Conditions                                                                                              | Min.                                                                  | Typ. | Max. | Units      |
|---------------|-----------------------------------------|---------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------|------|------|------------|
| $I_{QCCH}$    | Quiescent $V_{CC}$ Supply Current       | $V_{CC(H)} = 15V$ , $I_{N(UH,VH,WH)} = 0V$                                                              | $V_{CC(H)} - COM$                                                     | -    | -    | 0.10 mA    |
| $I_{QCCL}$    |                                         | $V_{CC(L)} = 15V$ , $I_{N(UL,VL,WL)} = 0V$                                                              | $V_{CC(L)} - COM$                                                     | -    | -    | 2.65 mA    |
| $I_{PCCH}$    | Operating $V_{CC}$ Supply Current       | $V_{CC(H)} = 15V$ , $f_{PWM} = 20kHz$ , duty=50%, applied to one PWM signal input for High-side         | $V_{CC(H)} - COM$                                                     | -    | -    | 0.15 mA    |
| $I_{PCCL}$    |                                         | $V_{CC(L)} = 15V$ , $f_{PWM} = 20kHz$ , duty=50%, applied to one PWM signal input for Low-side          | $V_{CC(L)} - COM$                                                     | -    | -    | 3.65 mA    |
| $I_{QBS}$     | Quiescent $V_{BS}$ Supply Current       | $V_{BS} = 15V$ , $I_{N(UH, VH, WH)} = 0V$                                                               | $V_{B(U)} - V_{S(U)}$ , $V_{B(V)} - V_{S(V)}$ , $V_{B(W)} - V_{S(W)}$ | -    | -    | 0.30 mA    |
| $I_{PBS}$     | Operating $V_{BS}$ Supply Current       | $V_{CC} = V_{BS} = 15V$ , $f_{PWM} = 20kHz$ , duty=50%, applied to one PWM signal input for High-side   | $V_{B(U)} - V_{S(U)}$ , $V_{B(V)} - V_{S(V)}$ , $V_{B(W)} - V_{S(W)}$ | -    | -    | 2.00 mA    |
| $V_{FOH}$     | Fault Output Voltage                    | $V_{SC} = 0V$ , $V_{FO}$ Circuit: 4.7k $\Omega$ to 5V Pull-up                                           | 4.5                                                                   | -    | -    | V          |
| $V_{FOL}$     |                                         | $V_{SC} = 1V$ , $V_{FO}$ Circuit: 4.7k $\Omega$ to 5V Pull-up                                           | -                                                                     | -    | 0.5  | V          |
| $V_{SC(ref)}$ | Short Circuit Trip Level                | $V_{CC} = 15V$ (Note 4)                                                                                 | 0.45                                                                  | 0.5  | 0.55 | V          |
| $UV_{CCD}$    | Supply Circuit Under-Voltage Protection | Detection Level                                                                                         | 10.5                                                                  | -    | 13.0 | V          |
| $UV_{CCR}$    |                                         | Reset Level                                                                                             | 11.0                                                                  | -    | 13.5 | V          |
| $UV_{BSD}$    |                                         | Detection Level                                                                                         | 10.0                                                                  | -    | 12.5 | V          |
| $UV_{BSR}$    |                                         | Reset Level                                                                                             | 10.5                                                                  | -    | 13.0 | V          |
| $t_{FOD}$     | Fault-out Pulse Width                   |                                                                                                         | 30                                                                    | -    | -    | $\mu s$    |
| $V_{IN(ON)}$  | ON Threshold Voltage                    | Applied between $I_{N(UH)}$ , $I_{N(VH)}$ , $I_{N(WH)}$ , $I_{N(UL)}$ , $I_{N(VL)}$ , $I_{N(WL)} - COM$ | -                                                                     | -    | 2.6  | V          |
| $V_{IN(OFF)}$ | OFF Threshold Voltage                   |                                                                                                         | 0.8                                                                   | -    | -    | V          |
| $R_{TH}$      | Resistance of Thermister                | @ $T_{TH}=25^\circ C$ , (Note 5)                                                                        | -                                                                     | 47   | -    | k $\Omega$ |
|               |                                         | @ $T_{TH}=100^\circ C$                                                                                  | -                                                                     | 2.9  | -    | k $\Omega$ |

## Note:

4. Short-circuit current protection is functioning only at the low-sides.

5.  $T_{TH}$  is the temperature of thermister itself. To know case temperature ( $T_C$ ), please make the experiment considering your application.



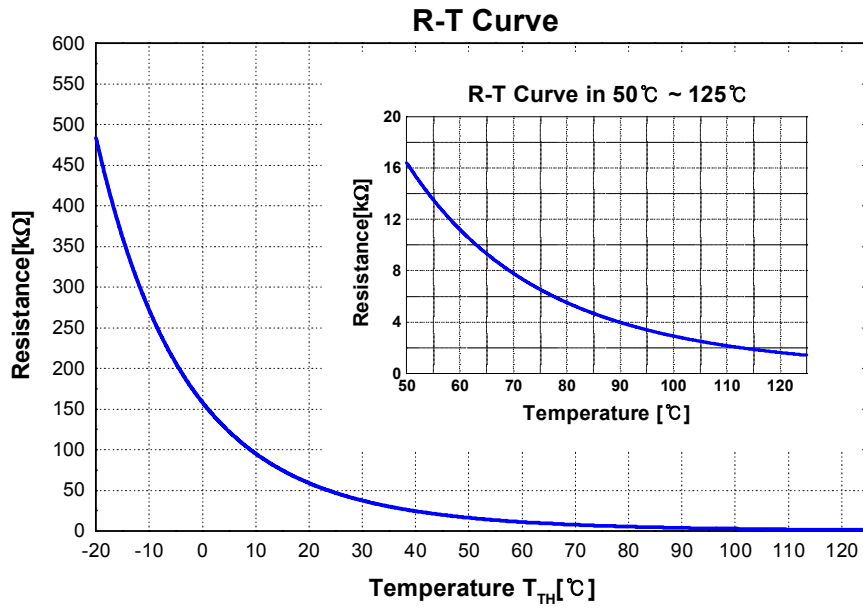
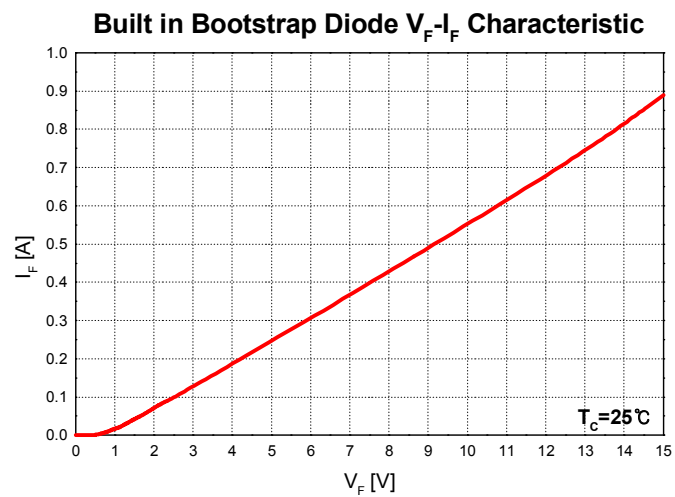


Figure. 6. R-T Curve of The Built-in Thermistor

#### Bootstrap Diode Part

| Symbol   | Parameter             | Conditions                     | Min. | Typ. | Max. | Units |
|----------|-----------------------|--------------------------------|------|------|------|-------|
| $V_F$    | Forward Voltage       | $I_F = 0.1A, T_C = 25^\circ C$ | -    | 2.5  | -    | V     |
| $t_{rr}$ | Reverse Recovery Time | $I_F = 0.1A, T_C = 25^\circ C$ | -    | 80   | -    | ns    |



**Note:**

6. Built in bootstrap diode includes around 15Ω resistance characteristic.

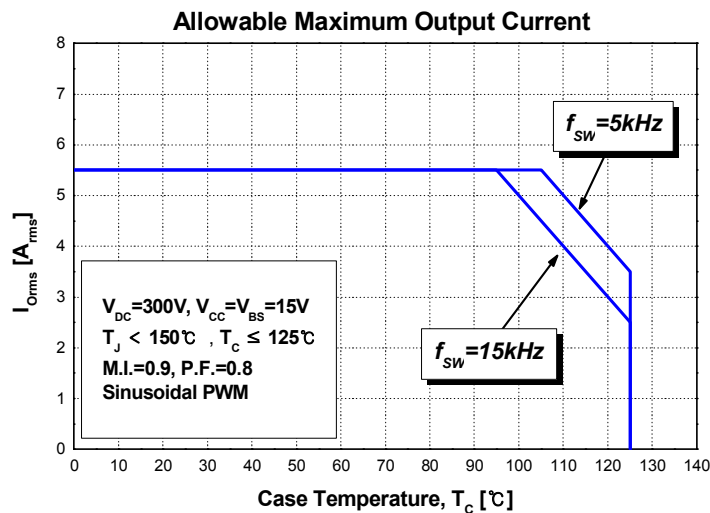
Figure 7. Built in Bootstrap Diode Characteristic

## Recommended Operating Conditions

| Symbol                         | Parameter                              | Conditions                                                                                  | Value |      |      | Units      |
|--------------------------------|----------------------------------------|---------------------------------------------------------------------------------------------|-------|------|------|------------|
|                                |                                        |                                                                                             | Min.  | Typ. | Max. |            |
| $V_{PN}$                       | Supply Voltage                         | Applied between P - $N_U$ , $N_V$ , $N_W$                                                   | -     | 300  | 400  | V          |
| $V_{CC}$                       | Control Supply Voltage                 | Applied between $V_{CC(H)}$ , $V_{CC(L)}$ -COM                                              | 13.5  | 15   | 16.5 | V          |
| $V_{BS}$                       | High-side Bias Voltage                 | Applied between $V_{B(U)}$ - $V_{S(U)}$ , $V_{B(V)}$ - $V_{S(V)}$ , $V_{B(W)}$ - $V_{S(W)}$ | 13.0  | 15   | 18.5 | V          |
| $dV_{CC}/dt$ ,<br>$dV_{BS}/dt$ | Control supply variation               |                                                                                             | -1    | -    | 1    | V/ $\mu$ s |
| $t_{dead}$                     | Blanking Time for Preventing Arm-short | For Each Input Signal                                                                       | 1.5   | -    | -    | $\mu$ s    |
| $f_{PWM}$                      | PWM Input Signal                       | $-40^{\circ}\text{C} < T_J < 150^{\circ}\text{C}$                                           | -     | -    | 20   | kHz        |
| $V_{SEN}$                      | Voltage for Current Sensing            | Applied between $N_U$ , $N_V$ , $N_W$ - COM (Including surge voltage)                       | -4    |      | 4    | V          |
| $P_{WIN(ON)}$                  | Minimum Input Pulse Width              | (Note 7)                                                                                    | 0.5   | -    | -    | $\mu$ s    |
| $P_{WIN(OFF)}$                 |                                        |                                                                                             | 0.5   | -    | -    |            |

### Note:

7. SPM might not make response if input pulse width is less than the recommended value.



### Note:

8. The allowable output current value may be different from the actual application.

**Figure 8. Allowable Maximum Output Current**

## Package Marking and Ordering Information

| Device Marking | Device     | Package   | Reel Size | Tape Width | Quantity |
|----------------|------------|-----------|-----------|------------|----------|
| FNA40860       | FNA40860   | SPM26-AAA | -         | -          | 12       |
| FNA40860B2     | FNA40860B2 | SPM26-AAC | -         | -          | 12       |

## Mechanical Characteristics and Ratings

| Parameter       | Conditions           | Limits               |      |      | Units         |
|-----------------|----------------------|----------------------|------|------|---------------|
|                 |                      | Min.                 | Typ. | Max. |               |
| Device Flatness | Note Figure 9        | 0                    | -    | +120 | $\mu\text{m}$ |
| Mounting Torque | Mounting Screw: - M3 | Recommended 0.7N•m   |      |      | N•m           |
|                 | Note Figure 10       | Recommended 7.1kg•cm |      |      | kg•cm         |
| Weight          |                      | -                    | 11   | -    | g             |

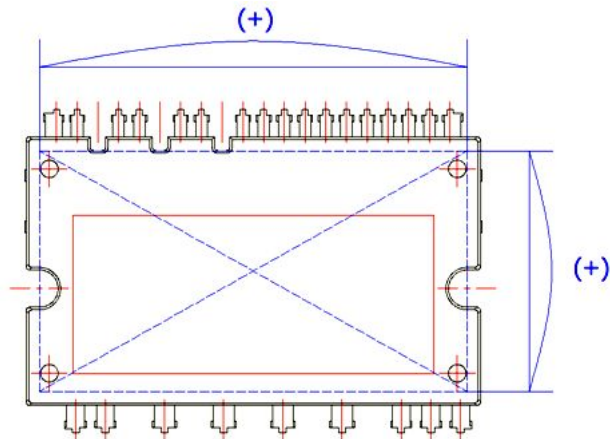
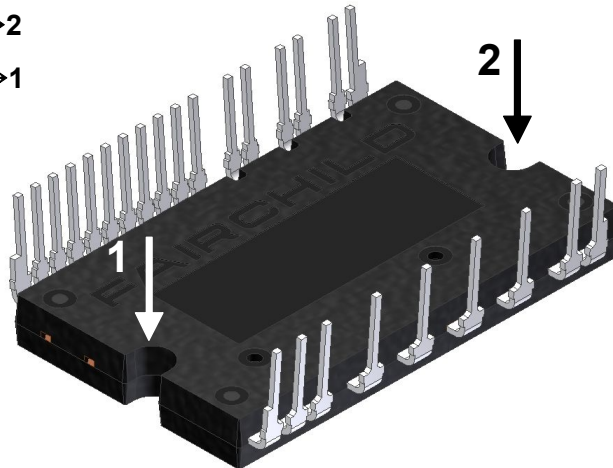


Figure 9. Flatness Measurement Position

**Pre - Screwing : 1→2**

**Final Screwing : 2→1**

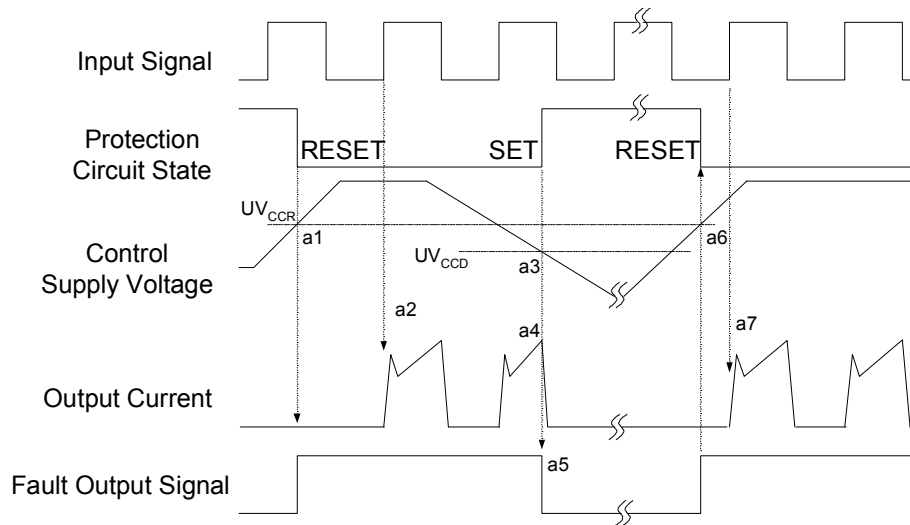


**Note:**

9. Do not make over torque when mounting screws. Much mounting torque may cause ceramic cracks, as well as bolts and Al heat-sink destruction.
10. Avoid one side tightening stress. Fig.10 shows the recommended torque order for mounting screws. Uneven mounting can cause the SPM ceramic substrate to be damaged.  
The Pre-Screwing torque is set to 20~30% of maximum torque rating.

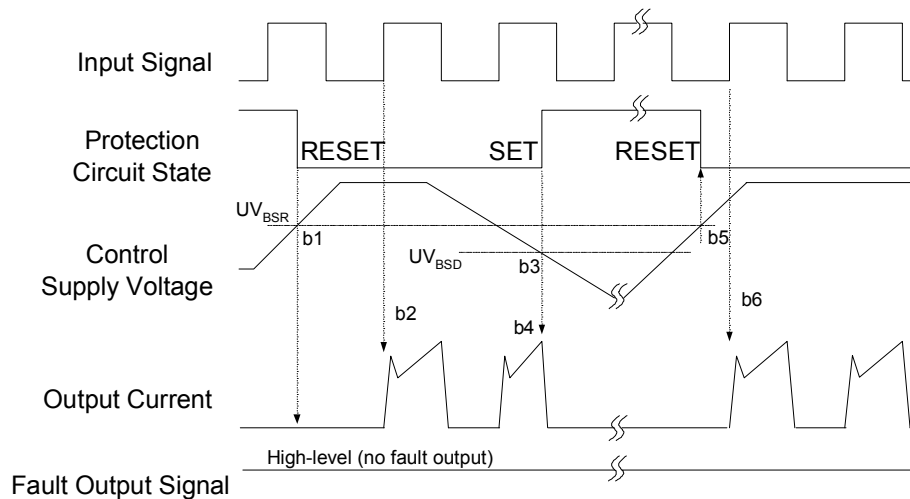
Figure 10. Mounting Screws Torque Order

## Time Charts of SPMs Protective Function



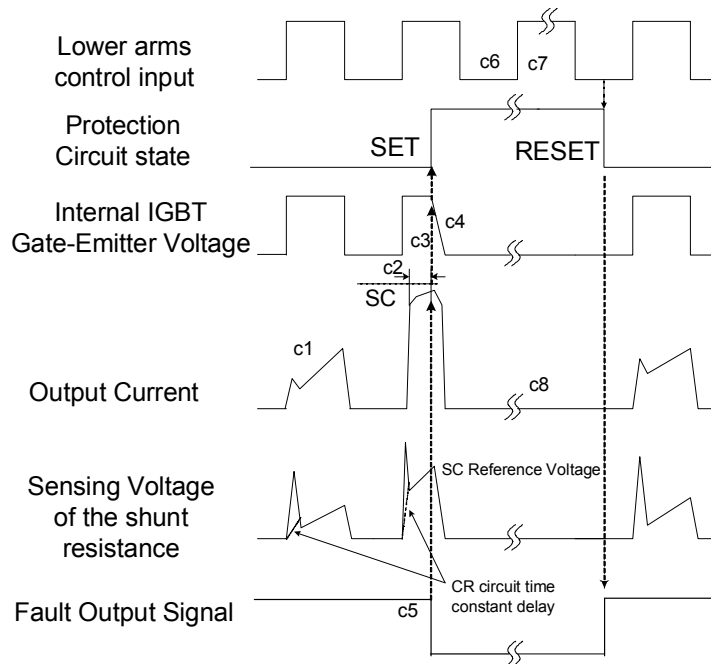
- a1 : Control supply voltage rises: After the voltage rises  $UV_{CCR}$ , the circuits start to operate when next input is applied.  
 a2 : Normal operation: IGBT ON and carrying current.  
 a3 : Under voltage detection ( $UV_{CCD}$ ).  
 a4 : IGBT OFF in spite of control input condition.  
 a5 : Fault output operation starts.  
 a6 : Under voltage reset ( $UV_{CCR}$ ).  
 a7 : Normal operation: IGBT ON and carrying current.

**Figure 11. Under-Voltage Protection (Low-side)**



- b1 : Control supply voltage rises: After the voltage reaches  $UV_{BSR}$ , the circuits start to operate when next input is applied.  
 b2 : Normal operation: IGBT ON and carrying current.  
 b3 : Under voltage detection ( $UV_{BSD}$ ).  
 b4 : IGBT OFF in spite of control input condition, but there is no fault output signal.  
 b5 : Under voltage reset ( $UV_{BSR}$ )  
 b6 : Normal operation: IGBT ON and carrying current

**Figure 12. Under-Voltage Protection (High-side)**



(with the external shunt resistance and CR connection)

c1 : Normal operation: IGBT ON and carrying current.

c2 : Short circuit current detection (SC trigger).

c3 : Hard IGBT gate interrupt.

c4 : IGBT turns OFF.

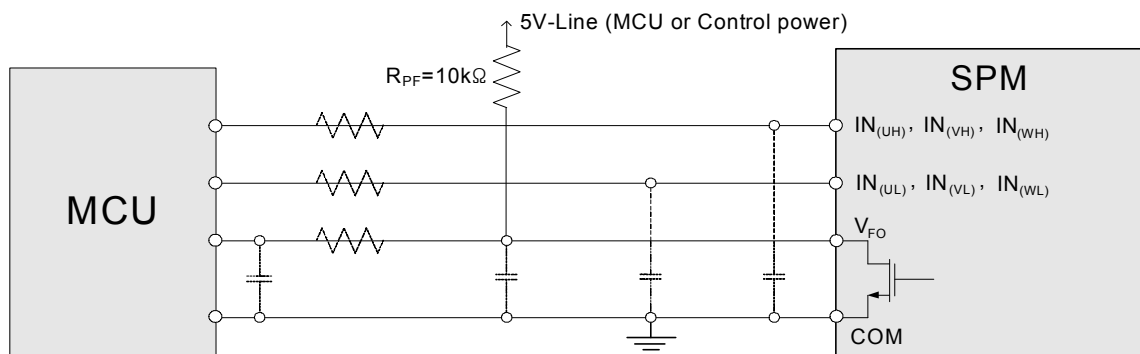
c5 : Input "L" : IGBT OFF state.

c6 : Input "H" : IGBT ON state, but during the active period of fault output the IGBT doesn't turn ON.

c7 : IGBT OFF state

**Figure 13. Short-Circuit Current Protection (Low-side Operation only)**

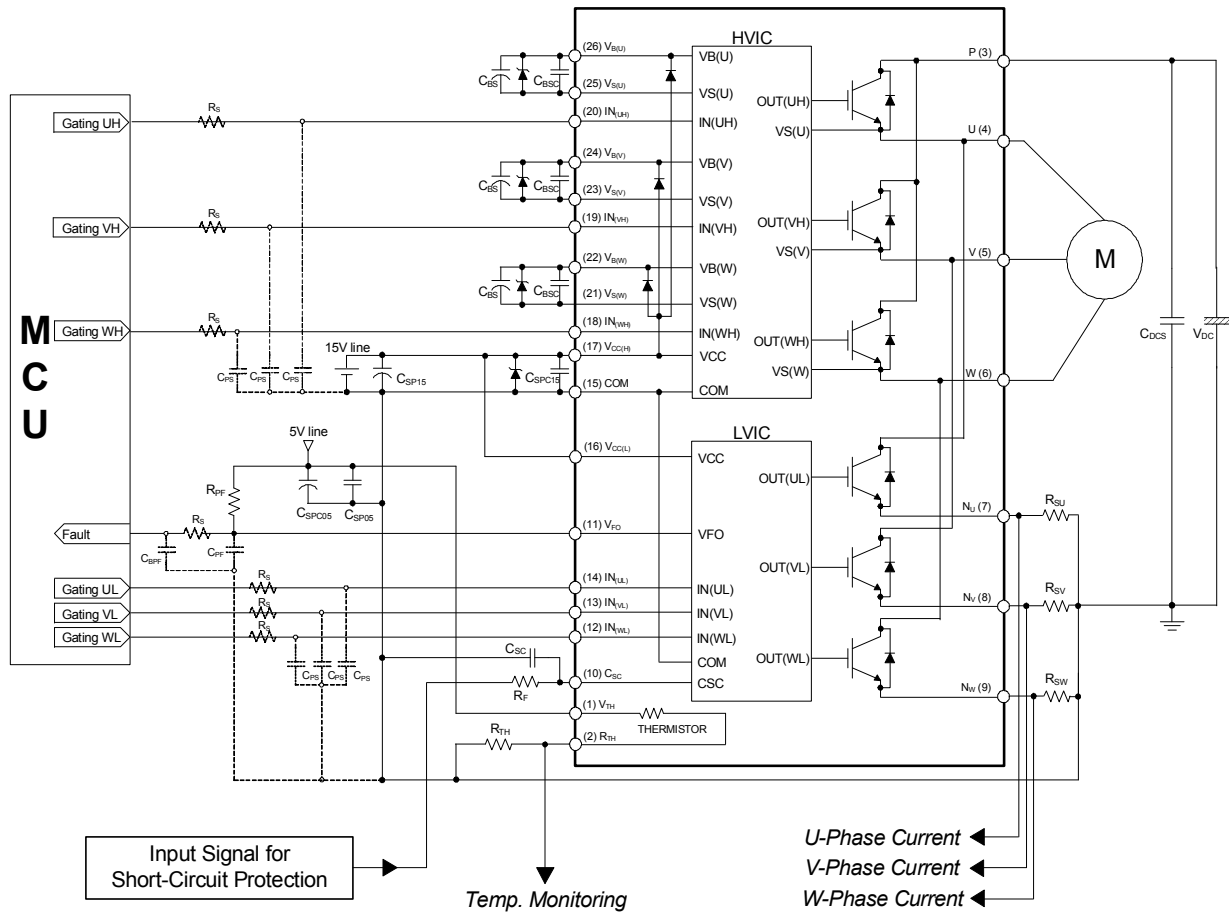
## Input/Output Interface Circuit



**Note:**

- 1) RC coupling at each input (parts shown dotted) might change depending on the PWM control scheme used in the application and the wiring impedance of the application's printed circuit board. The SPM input signal section integrates 5kΩ (typ.) pull-down resistor. Therefore, when using an external filtering resistor, please pay attention to the signal voltage drop at input terminal.
- 2) The logic input is compatible with standard CMOS outputs.

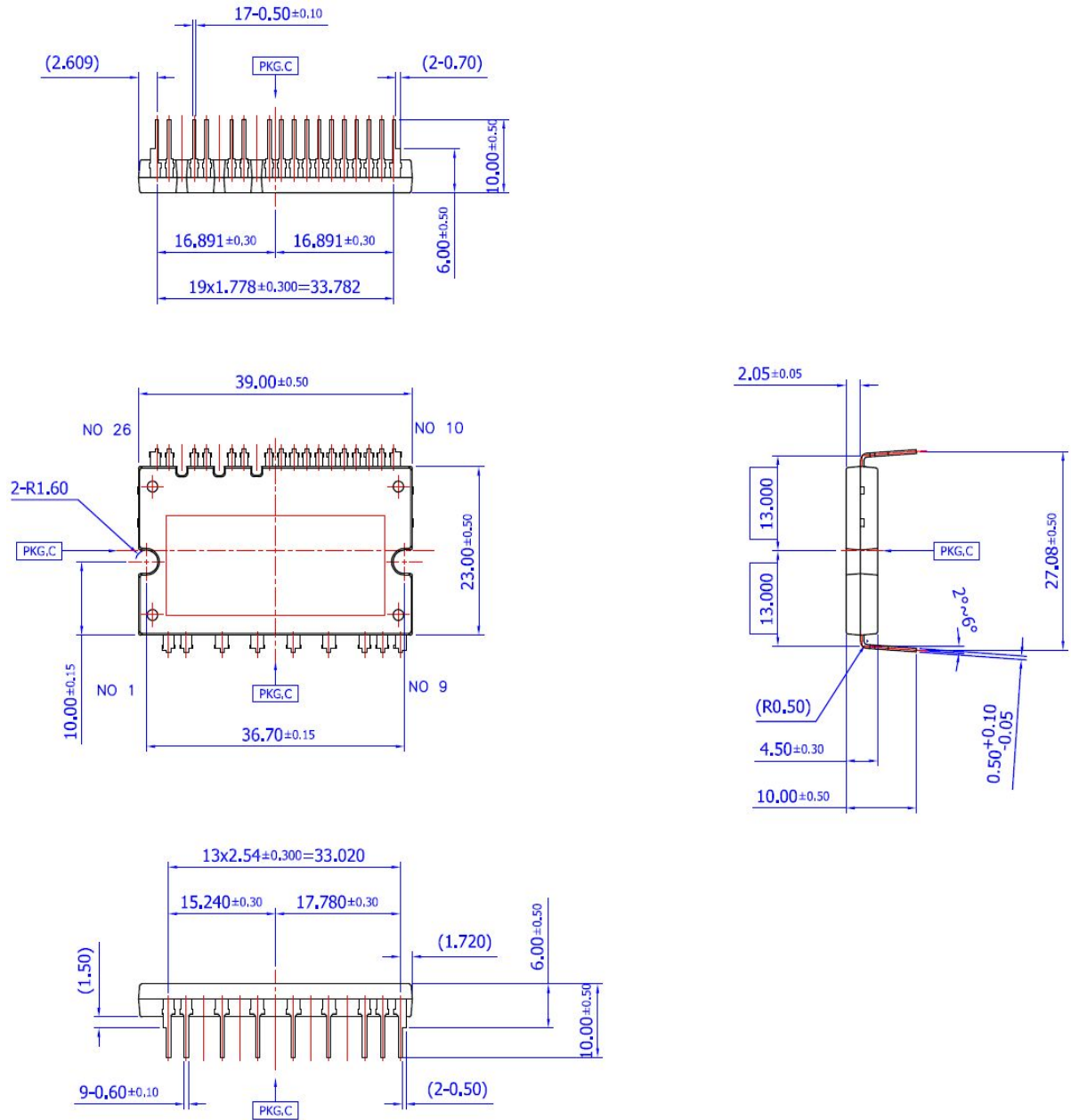
**Figure 14. Recommended CPU I/O Interface Circuit**

**Note:**

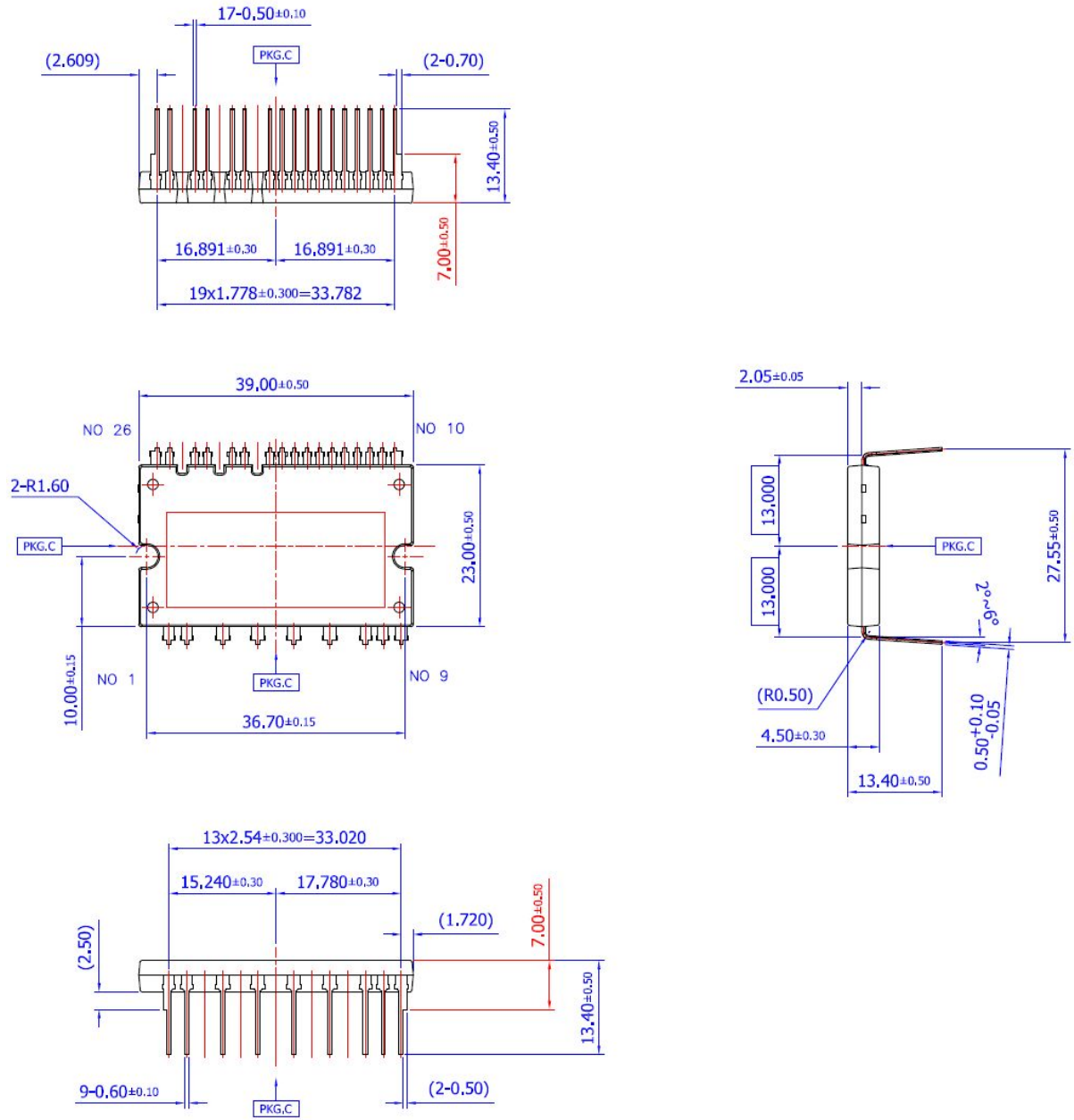
- 1) To avoid malfunction, the wiring of each input should be as short as possible. (less than 2-3cm)
- 2) By virtue of integrating an application specific type HVIC inside the SPM, direct coupling to CPU terminals without any opto-coupler or transformer isolation is possible.
- 3) VFO output is open drain type. This signal line should be pulled up to the positive side of the MCU or control power supply with a resistor that makes  $I_{FO}$  up to 1mA. Please refer to Figure14.
- 4)  $C_{SP15}$  of around 7 times larger than bootstrap capacitor  $C_{BS}$  is recommended.
- 5) Input signal is High-Active type. There is a  $5k\Omega$  resistor inside the IC to pull down each input signal line to GND. RC coupling circuits is recommended for the prevention of input signal oscillation.  $R_S C_{PS}$  time constant should be selected in the range 50~150ns. (Recommended  $R_S=100\Omega$ ,  $C_{PS}=1nF$ )
- 6) To prevent errors of the protection function, the wiring around  $R_F$  and  $C_{SC}$  should be as short as possible.
- 7) In the short-circuit protection circuit, please select the  $R_F C_{SC}$  time constant in the range 1.5~2 $\mu s$ .
- 8) Each capacitor should be mounted as close to the pins of the SPM as possible.
- 9) To prevent surge destruction, the wiring between the smoothing capacitor and the P&GND pins should be as short as possible. The use of a high frequency non-inductive capacitor of around 0.1~0.22 $\mu F$  between the P&GND pins is recommended.
- 10) Relays are used at almost every systems of electrical equipments of home appliances. In these cases, there should be sufficient distance between the CPU and the relays.
- 11) The zener diode should be adopted for the protection of ICs from the surge destruction between each pair of control supply terminals. (Recommended zener diode=24V/1W)
- 12) Please choose the electrolytic capacitor with good temperature characteristic in  $C_{BS}$ . Also, choose 0.1~0.2 $\mu F$  R-category ceramic capacitors with good temperature and frequency characteristics in  $C_{BSC}$ .
- 13) For the detailed information, please refer to the AN-9070 and FEB305-001.

**Figure 15. Typical Application Circuit**

# Detailed Package Outline Drawings(FNA40860)



# Detailed Package Outline Drawings(FNA40860B2, Long Terminal Type)







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